

# All-optical nanoscale temperature sensing on microelectronics using diamond quantum emitters

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21<sup>st</sup> Recontres du Vietnam





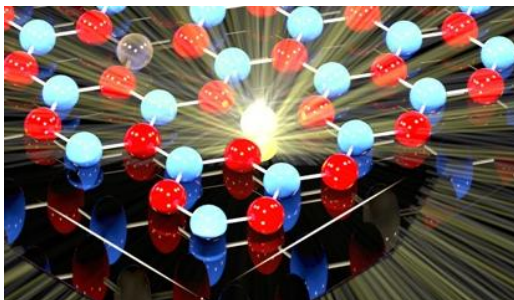
# Where we are: UTS Tech Lab (Botany NSW)

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<https://www.tttranlab.com/>

**Quantum defect in hBN**



**Quantum defect in diamond**



# Our group

## Current PhD students

Mr. Shakhawath Hossain



Mr. Nhat Minh Nguyen



Mr. Trung Vuong



## Alumni

Dr. Thi Ngoc Anh MAI



Postdoc UTS

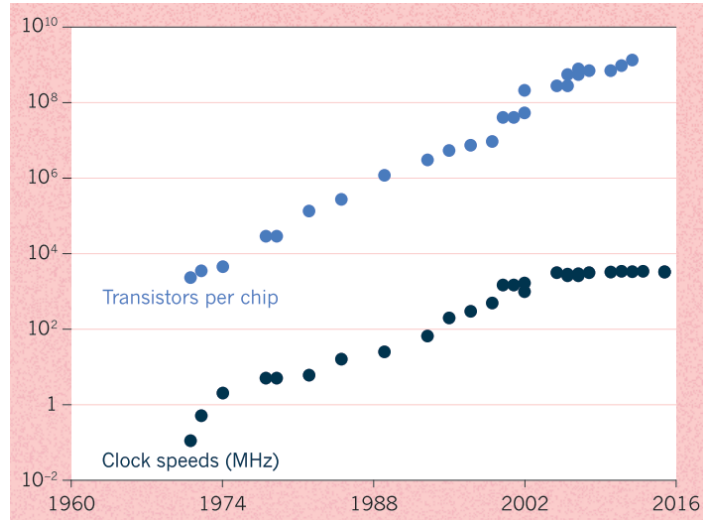
Dr. Yongliang Chen



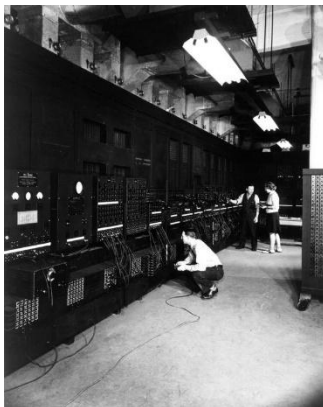
Postdoc U HK



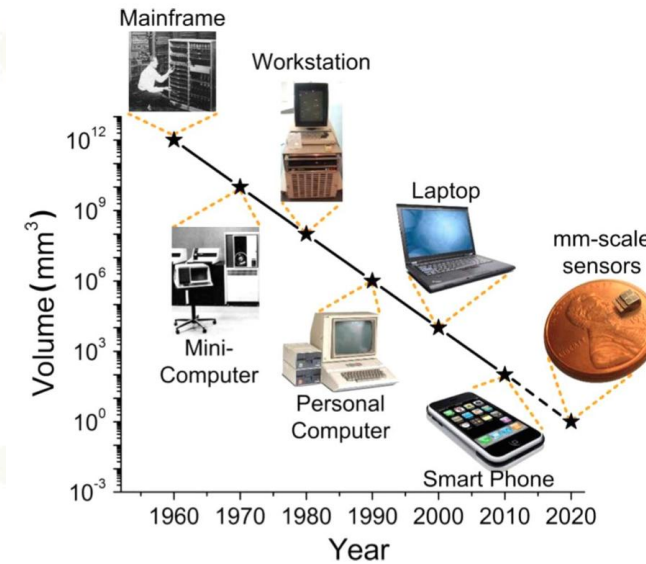
# Moore's law



Waldrop, M. M., *Nature News* 2016, 530, 144.



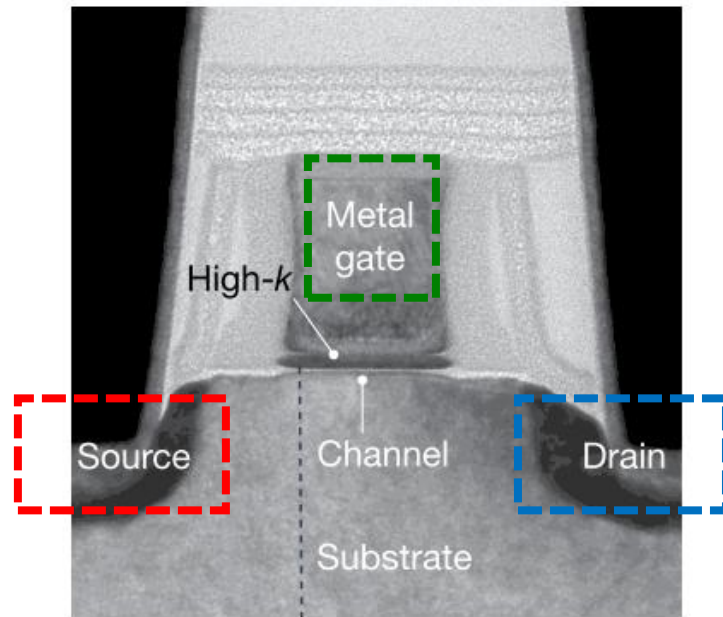
**ENIAC the first computer in 1945**



computerhistory.org

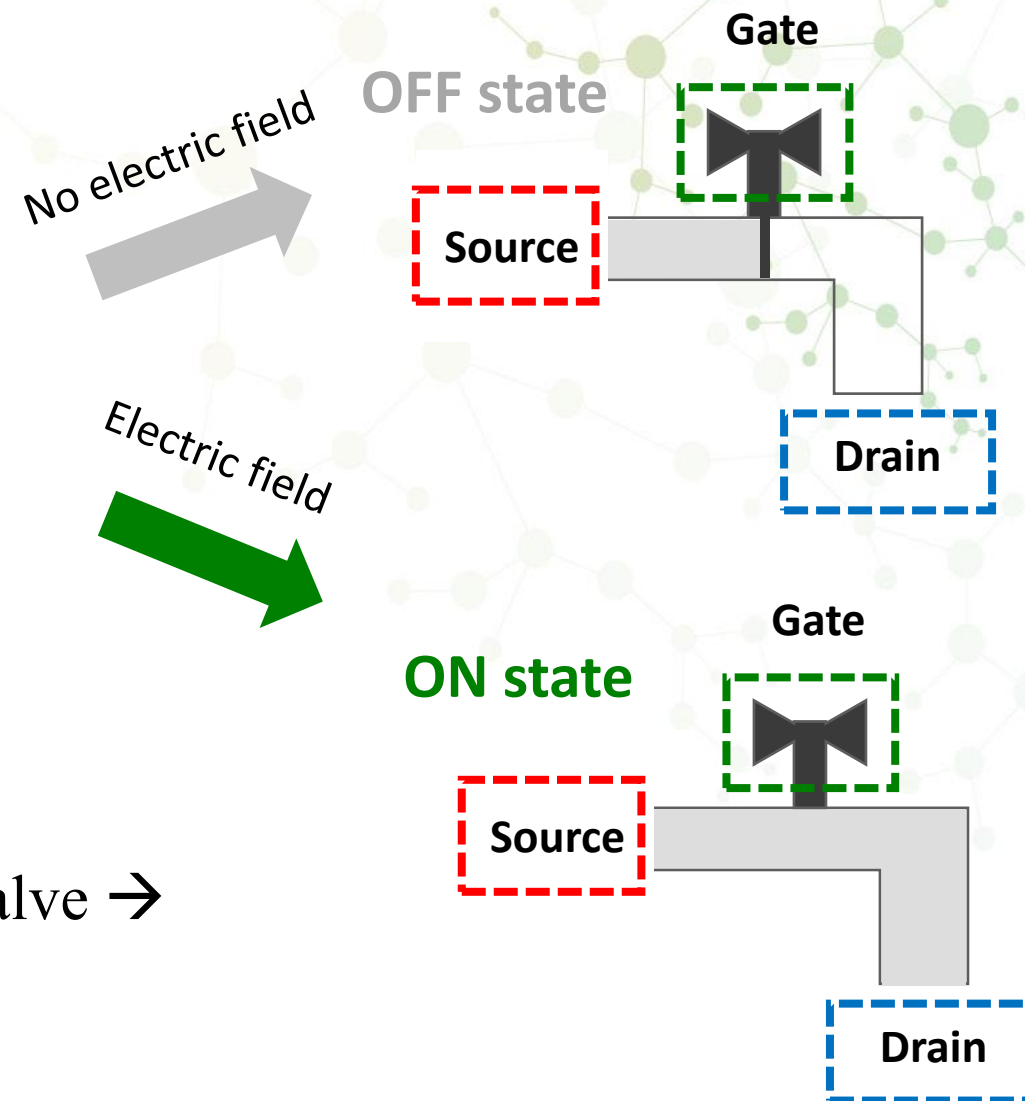
- Transistor number doubled every ~2 years
- Electronic devices significantly reduced in sizes

# Field-effect transistors: an electricity “water tap”

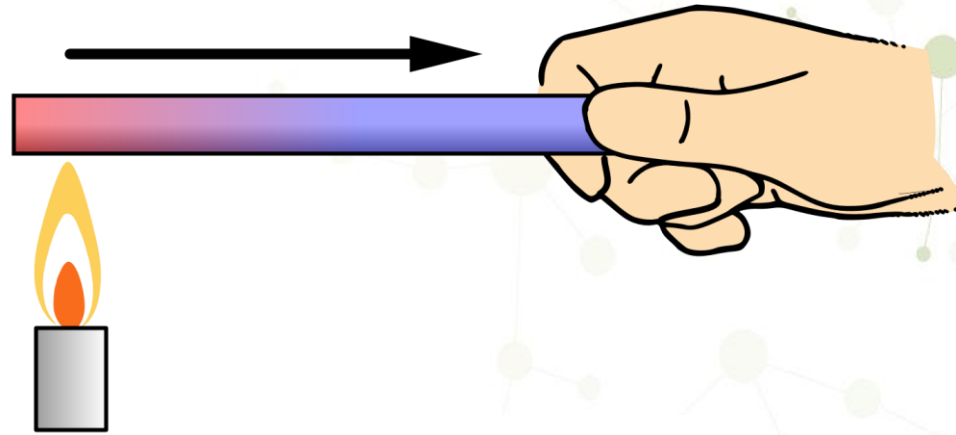


45-nm node planar n-MOSFET

- Applying electric field → open the valve → water flows



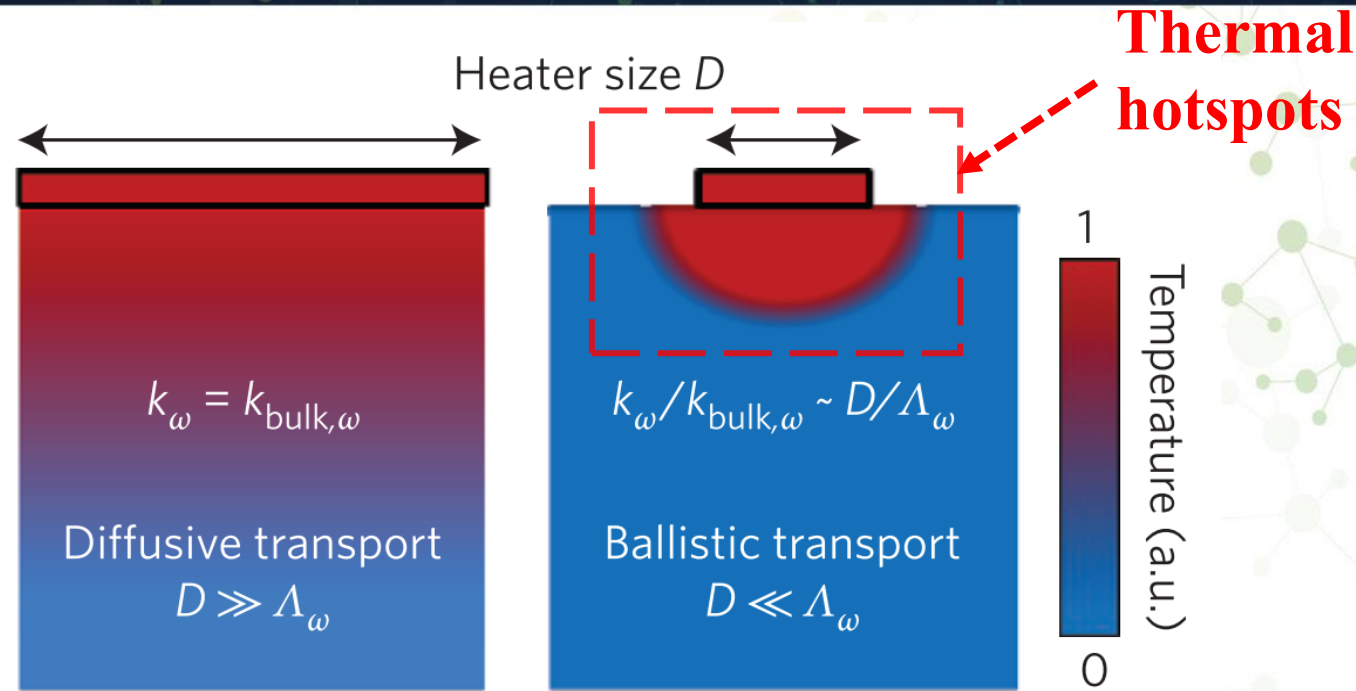
# Heat conduction at macroscopic scale



$$\mathbf{q} = -k\nabla T$$

- Fourier's law: rate of heat flow per unit area proportional to the negative temperature gradient – **diffusive regime**
  - $\mathbf{q}$  is the local heat flux density,  $\text{W/m}^2$ ,
  - $k$  is the material's **conductivity**,  $\text{W}/(\text{m}\cdot\text{K})$ ,
  - $\nabla T$  is the temperature gradient,  $\text{K/m}$ .

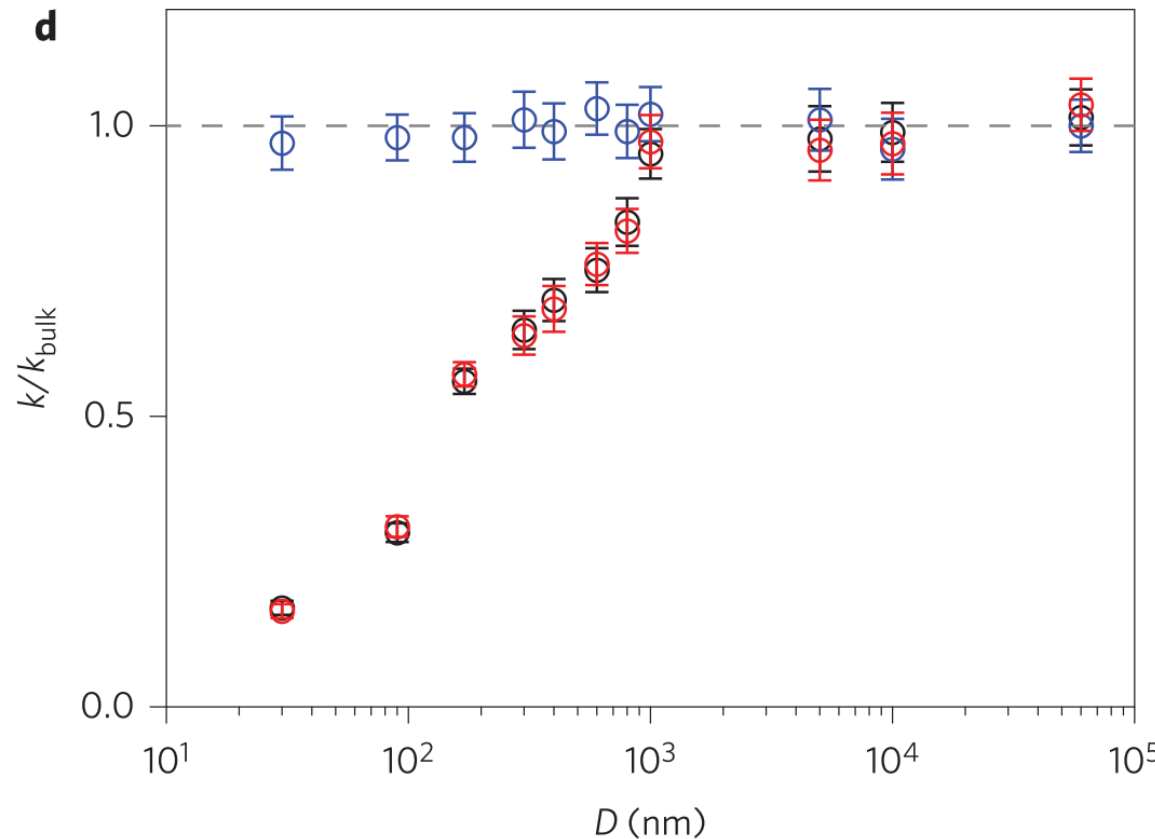
# Heat conduction at nanoscale



- When heater size smaller than the phonon mean free path (MFP), the average distance phonon travelling before a collision, **ballistic transport** takes over
- These phonons having no chance to pass on their momenta to the neighboring “hot” phonons and disappearing within their short “lifetime” → ***Fourier’s law breaks down! Thermal hot spots formed!***

# Heat conduction at nanoscale

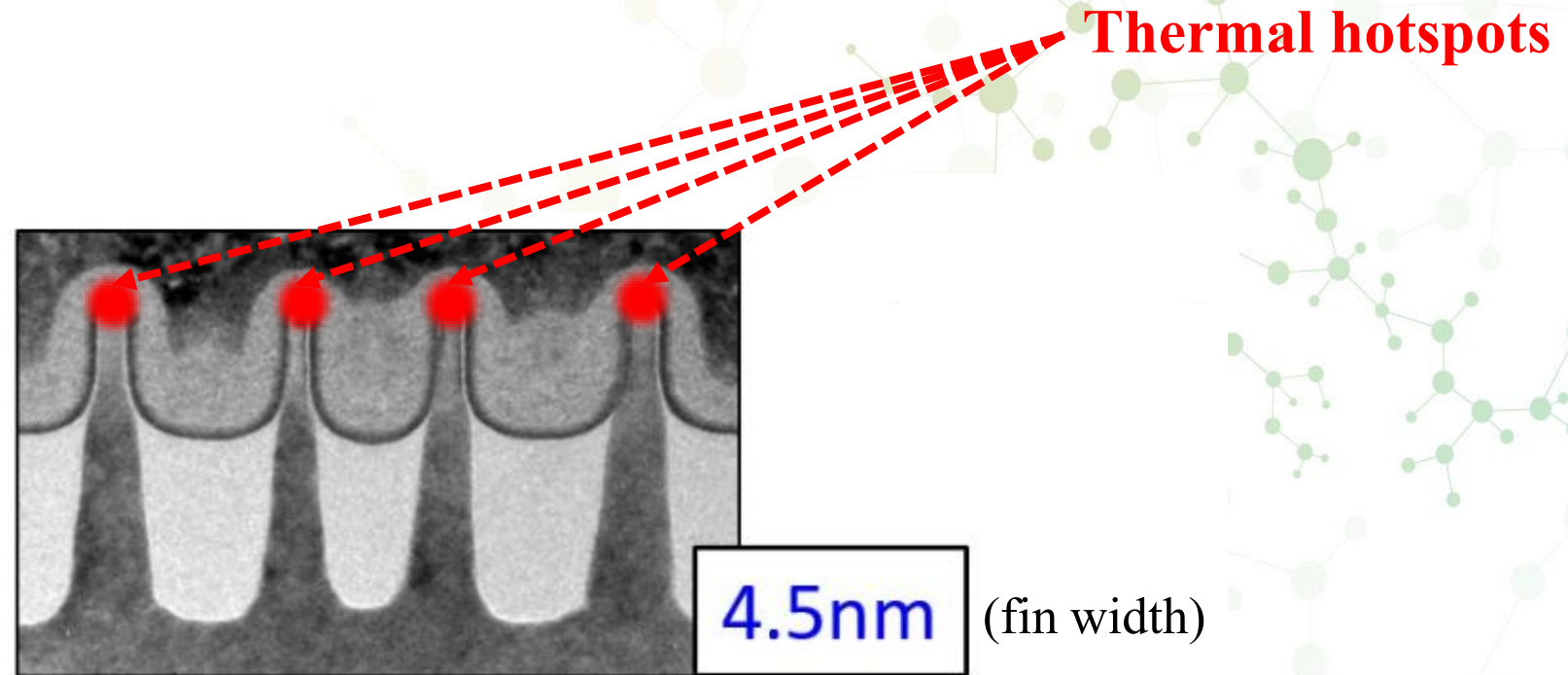
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- When heater size smaller than 1  $\mu\text{m}$ , the thermal conductivities drops significantly due to the ballistic transport effect



# Thermal hot spots formed in MOSFET



- As the transistor's dimensions shrink, *thermal hot spots will form at the conducting channel* due to ballistic thermal transport
- *How can we see these hot spots?*

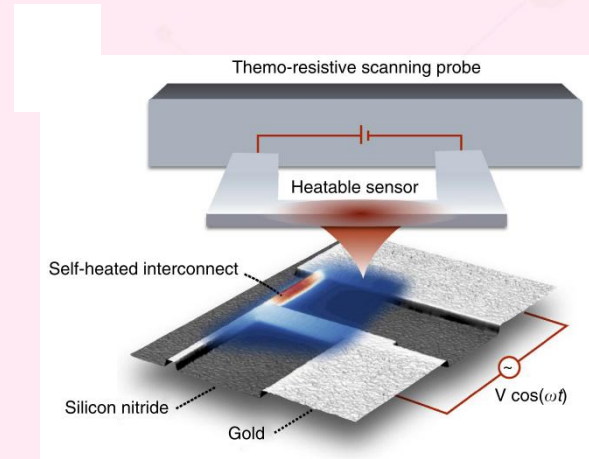
## IR thermography



fluke.com

- Planck's black body radiation
- + inexpensive, non-contact, mature technology
  - emissivity data required, low spatial resolution.

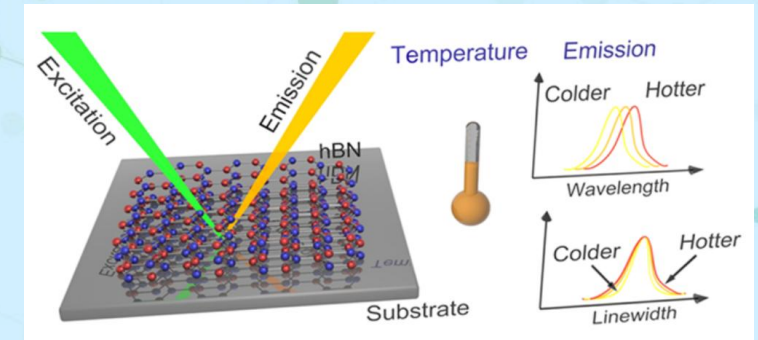
## Scanning thermal microscope



Menges, F.; *Nat. Commun.* 2016, 7, 10874.

- Resistance changes based on sharp, scanning tip
- + very high spatial resolution
  - complicated heat transfer, expensive, cumbersome

## Fluorescence / Optical thermometry

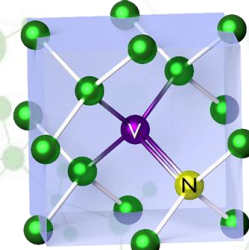
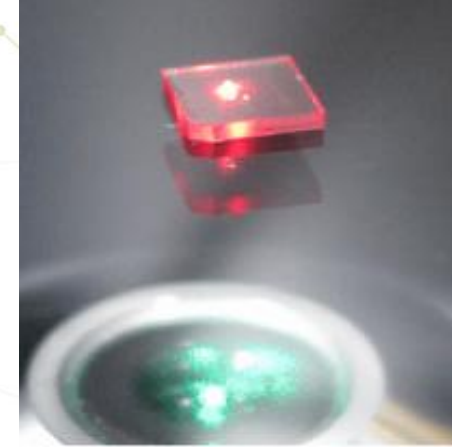
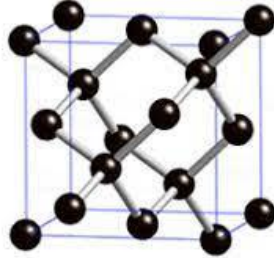


Chen, Y. *ACS Appl. Mater. Interfaces* 2020, 12, 25464

- Temperature-dependent fluorescence changes
- + high spatial resolution, non-contact, inexpensive, portable
  - low temporal resolution, difficult to do thermal mapping

# Color centers in diamond

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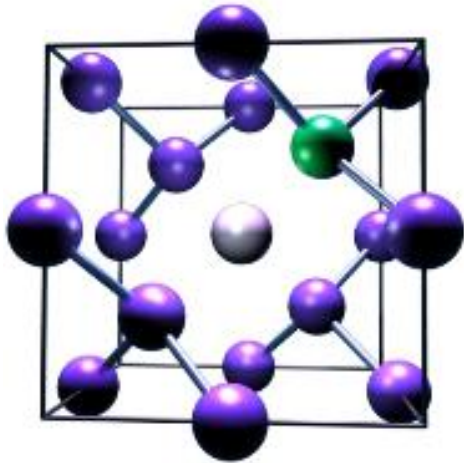


- Pure diamond has no color due to its large bandgap
- Diamond is among the most inert and durable → ideal for high temperature sensing

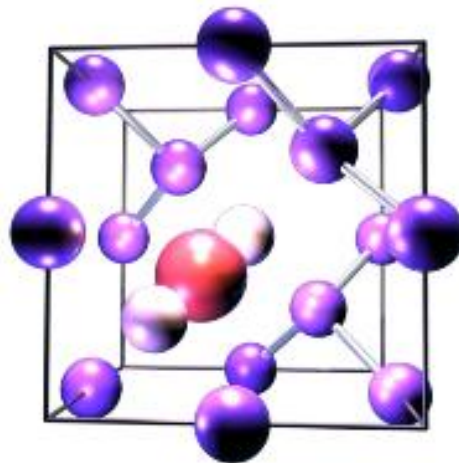
- When doped with impurities, diamond has a color due to defect complexes known as “color centers” or “quantum emitters”



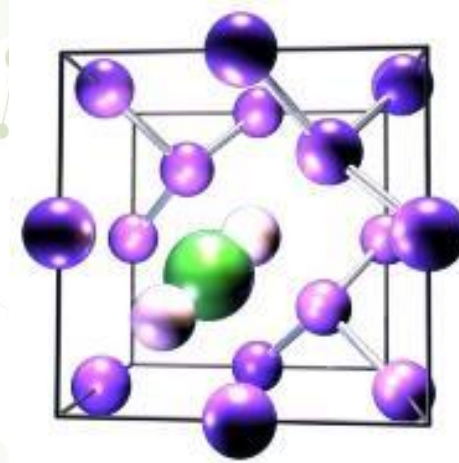
**NV center**



**SiV center**



**GeV center**

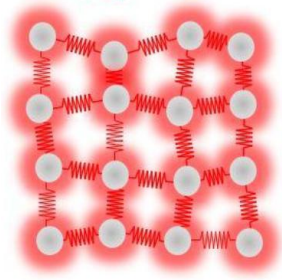


- There are tens of defect complexes in diamond
- Each having their own energy levels and hence their unique optical properties

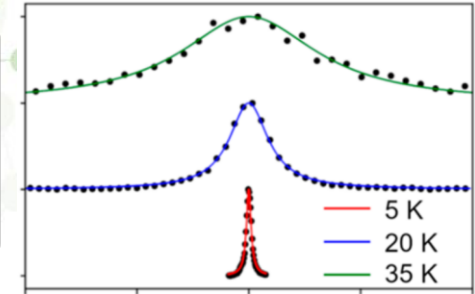
# Our approaches to optical thermometry

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**1. Anti-Stokes/Stokes ratio: stealing phonon energy**

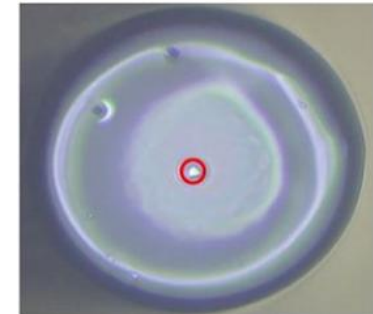


**2. Linewidth-temperature dependent: phonon dephasing**

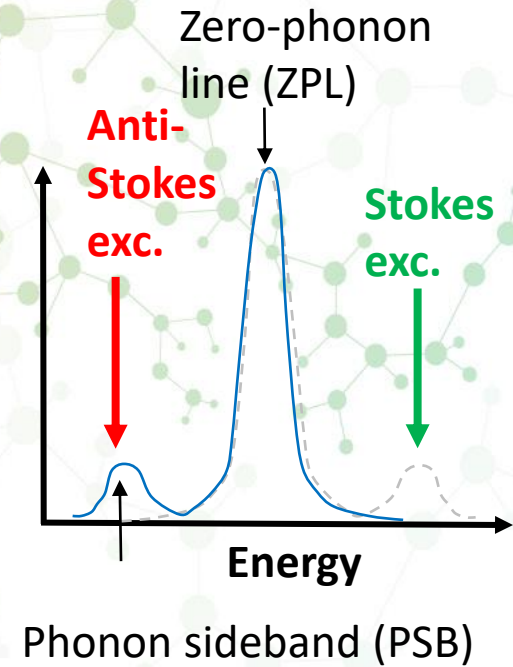
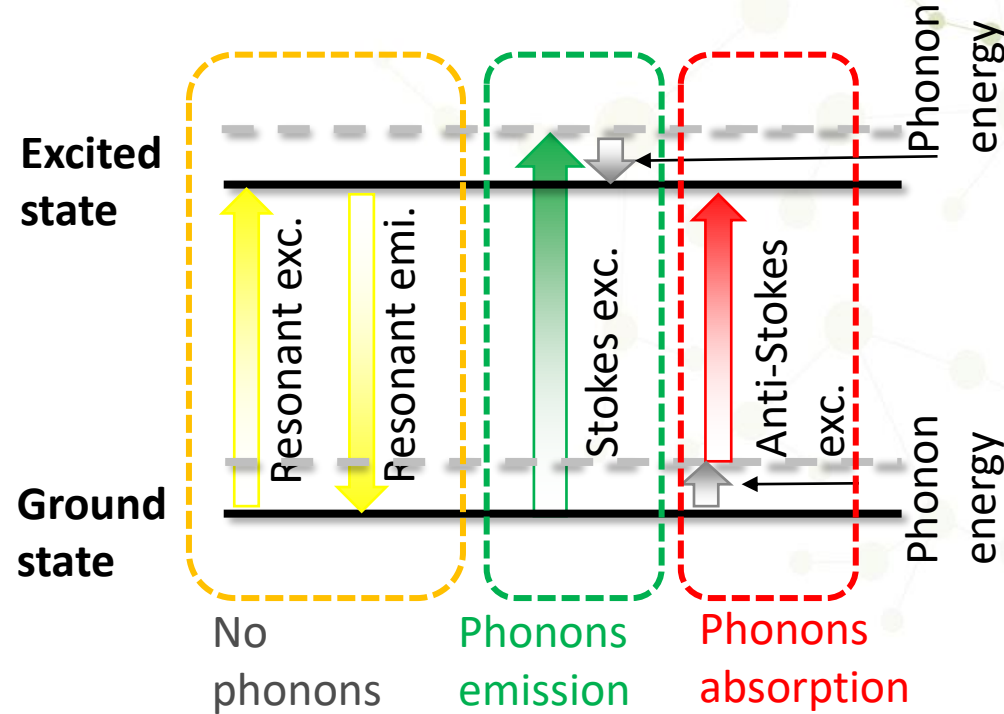
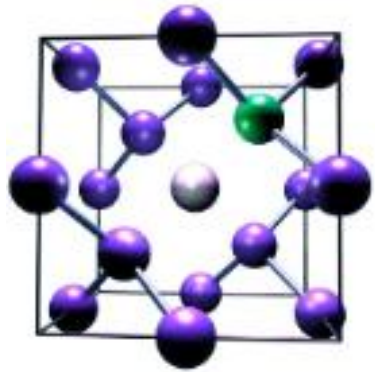


**Temperature-dependent observables**

**3. Fiber-based PL-to-scattered-laser ratio**



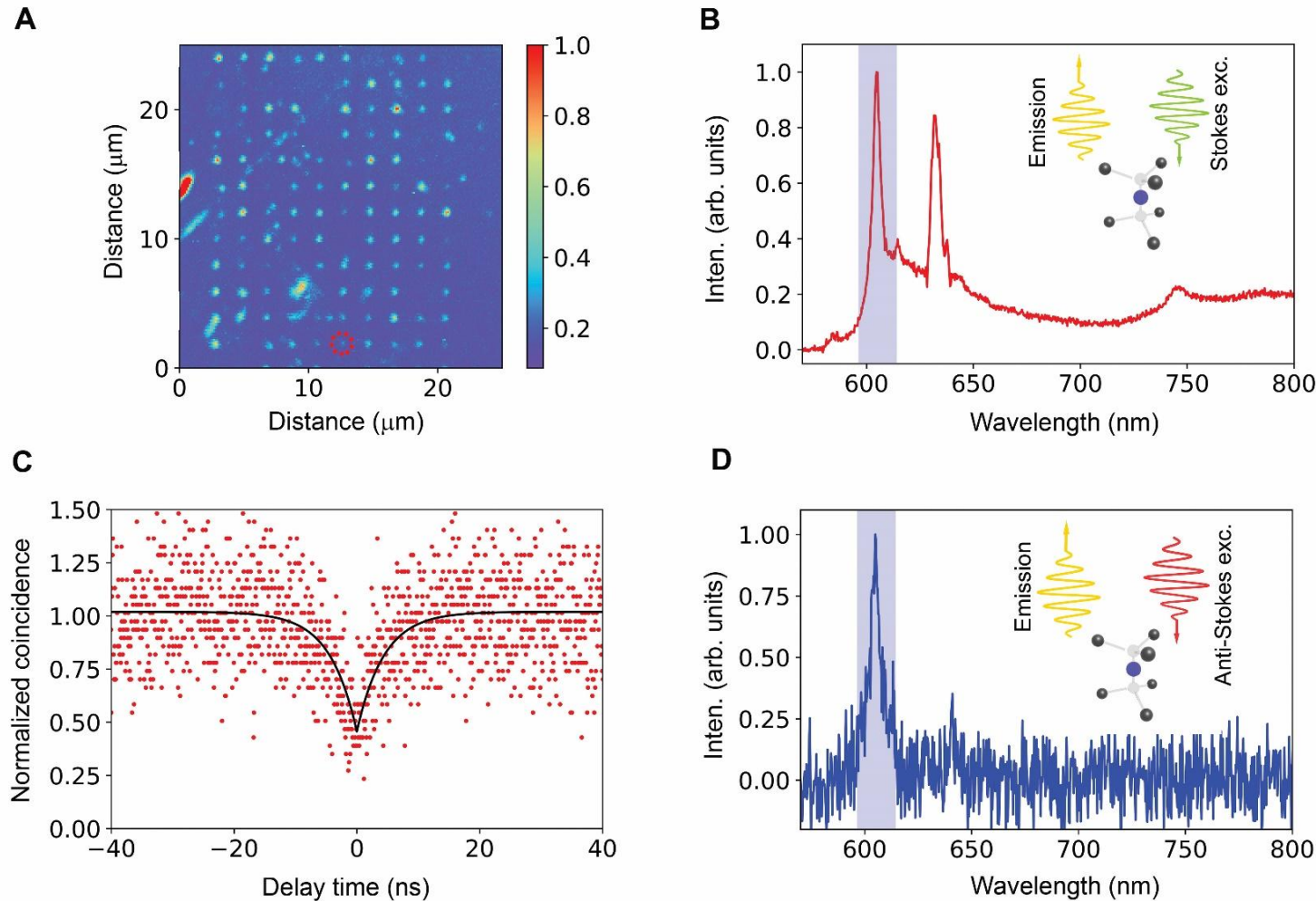
# 1. Anti-Stokes/Stokes ratio: stealing phonon energy



- Excitation energy can be **below** or **above** optical transition



# 1. Anti-Stokes/Stokes ratio: stealing phonon energy



532 nm excitation

Stokes exc.

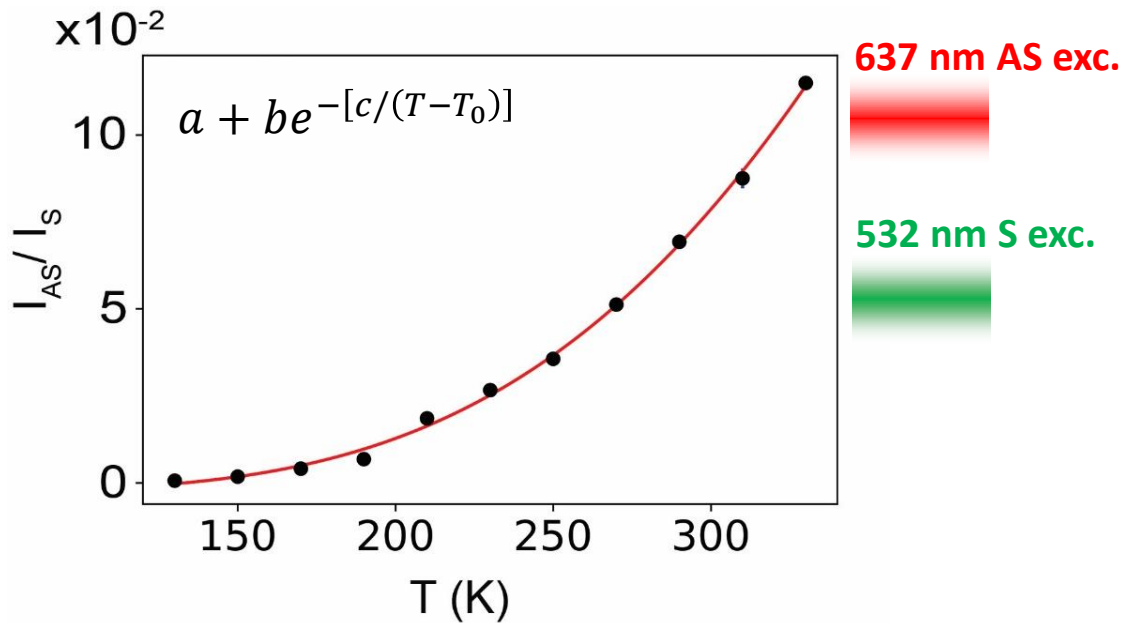
637 nm excitation

Anti-Stokes exc.

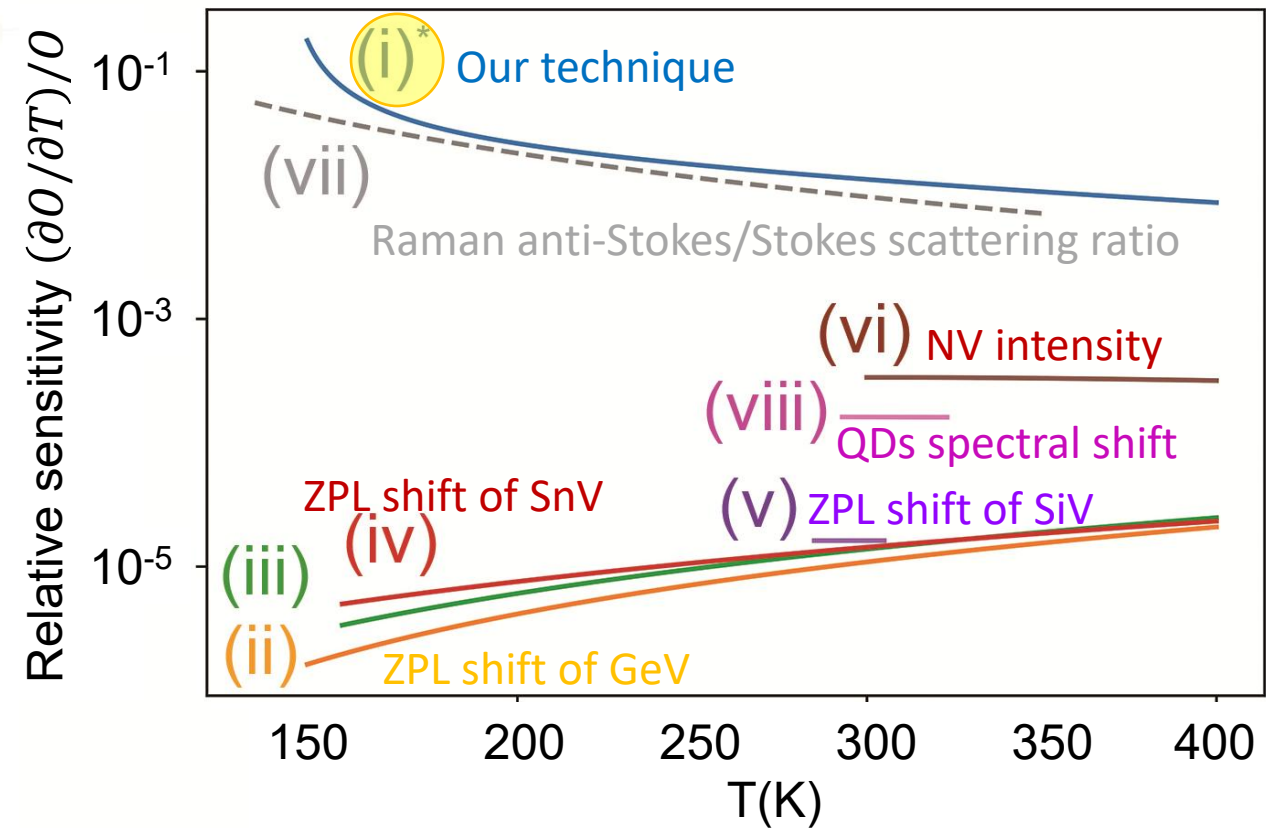
- Anti-Stokes excitation on a single GeV color center possible!

# 1. Anti-Stokes/Stokes ratio: stealing phonon energy

- Arrhenius-type exponential scaling with temperature

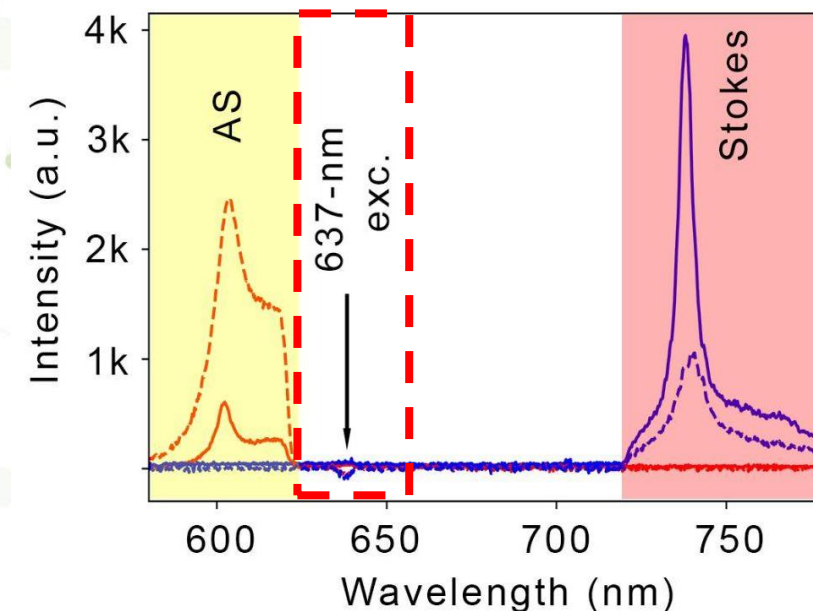
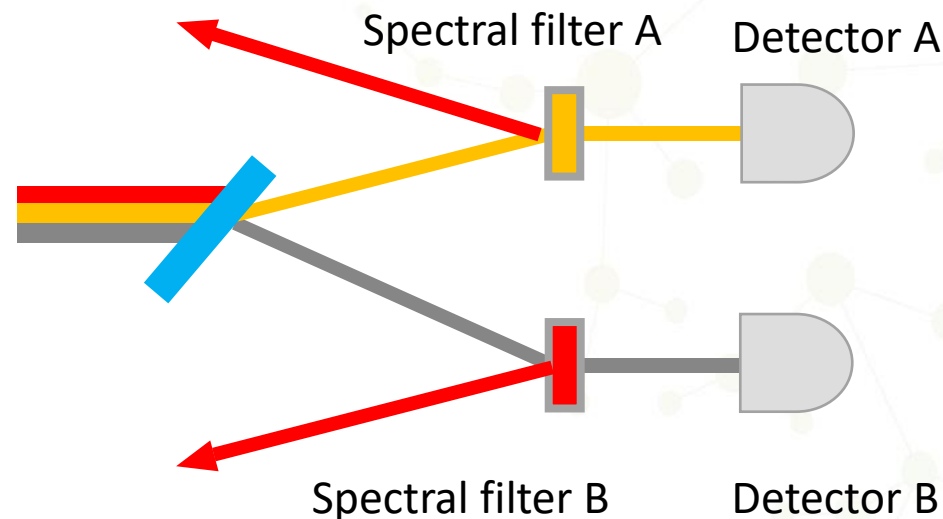
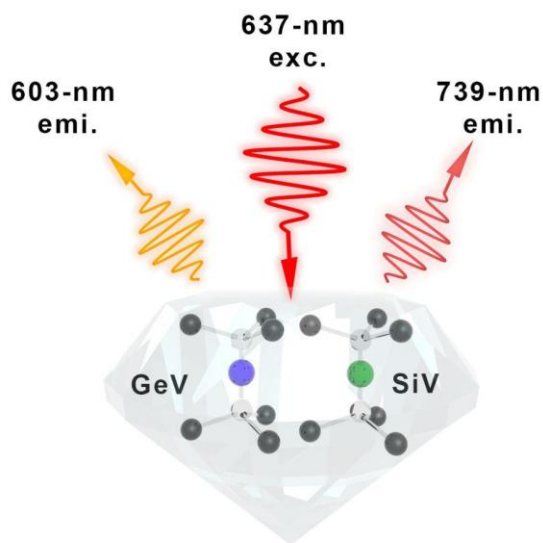


Resolution:  $455 \text{ mK} \cdot \text{Hz}^{-1/2}$  at 300K  
 $2.494 - 0.420 \text{ K} \cdot \text{Hz}^{-1/2}$  over 110–330 K



- High relative sensitivity due to exponential scaling!

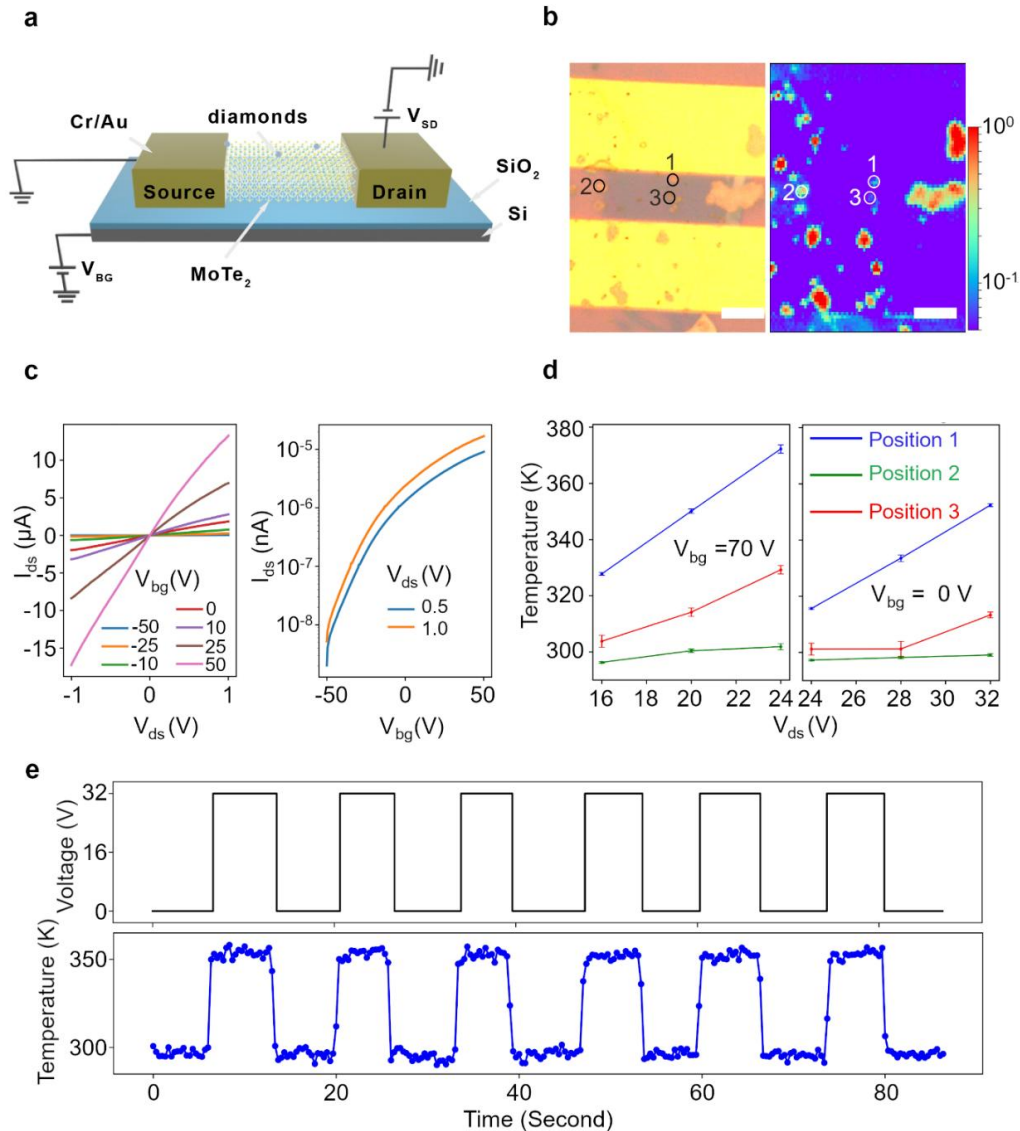
# 1. Anti-Stokes/Stokes ratio: stealing phonon energy



- Greatly simplifying the scheme by combining co-doping GeV and SiV on the same nanodiamond and utilizing spectral filtering & photon counting

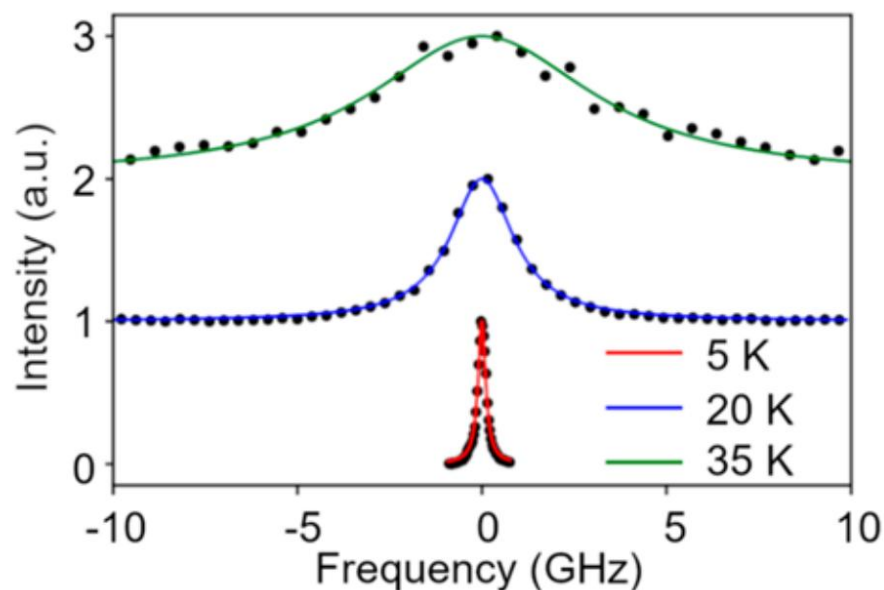
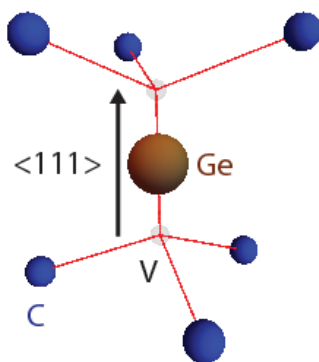
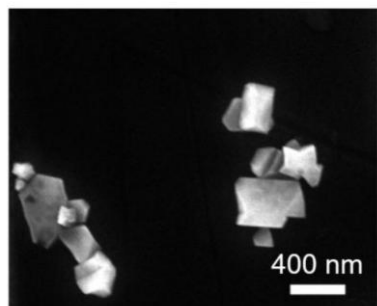


# 1. Anti-Stokes/Stokes ratio: stealing phonon energy



- Real-time local temperature monitoring of a MoTe<sub>2</sub> field-effect transistor using nanodiamonds.
- The ND (#1) close to the electrode showing largest temperature increase
- Temperature responding well to the changes in the input voltage

## 2. Linewidth-temperature dependent: phonon dephasing

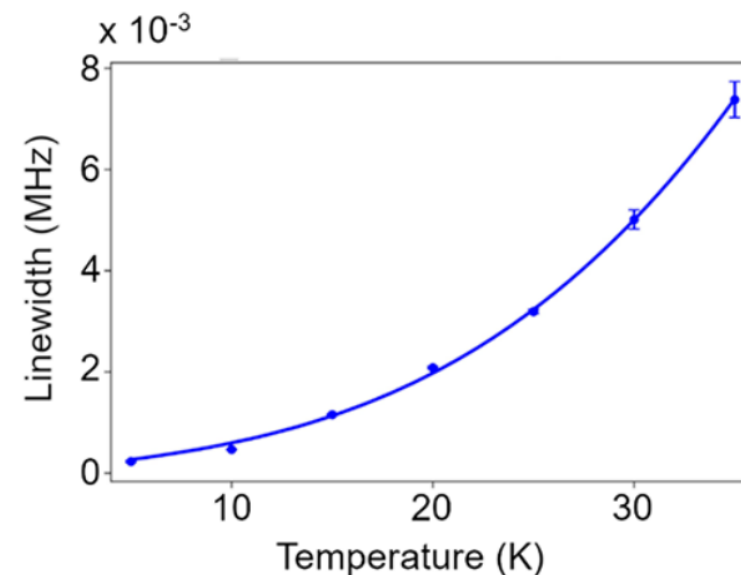


Lifetime-  
broadened term

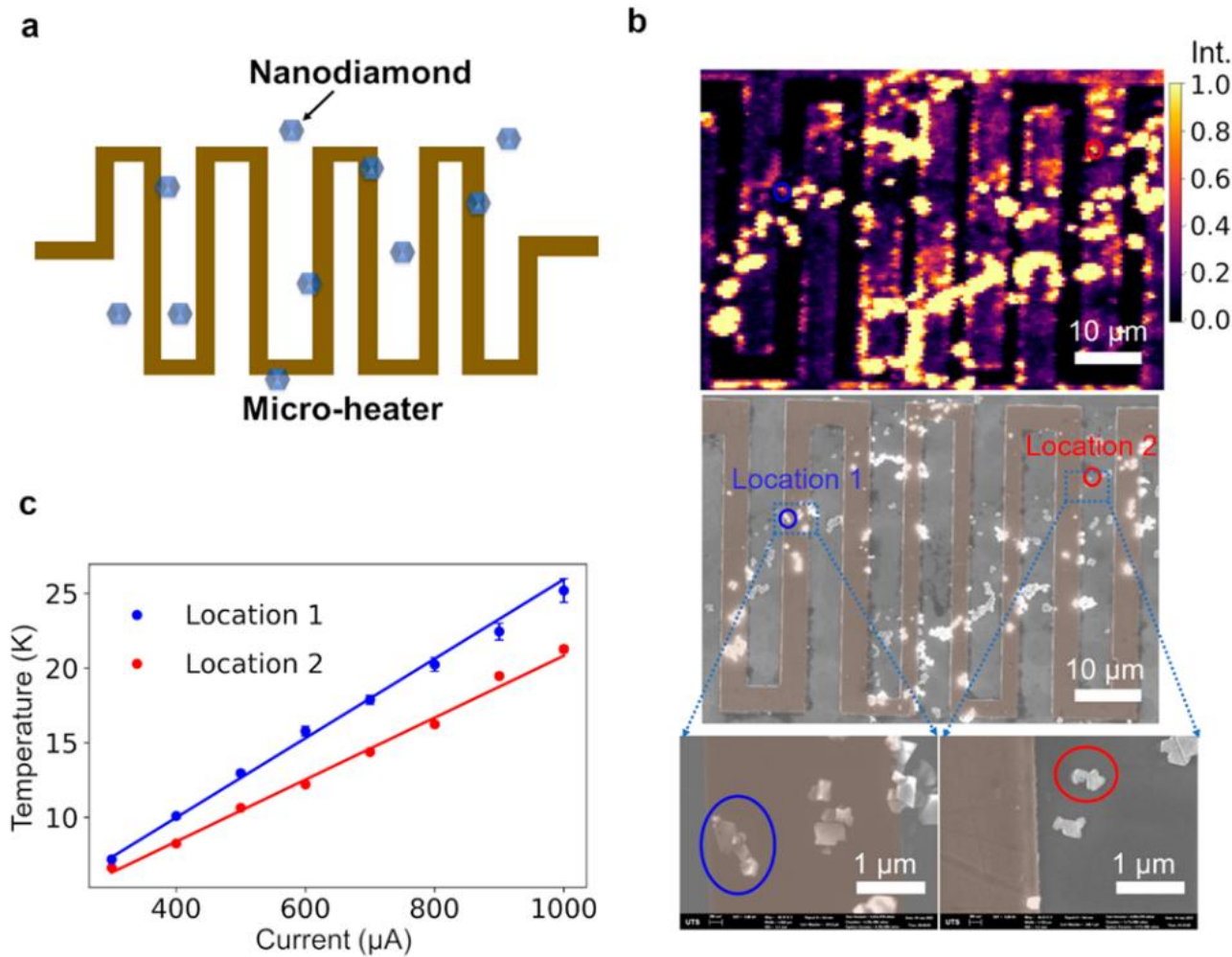
electron-phonon  
interaction term

$$\gamma_{\text{tot}} = \gamma_{\text{lt}} + \gamma_{\text{first}} + \gamma_{\text{second}} = c + bT + aT^3$$

- By using photoluminescence excitation (PLE) at low temperatures, we can determine and correlate linewidths with temperatures



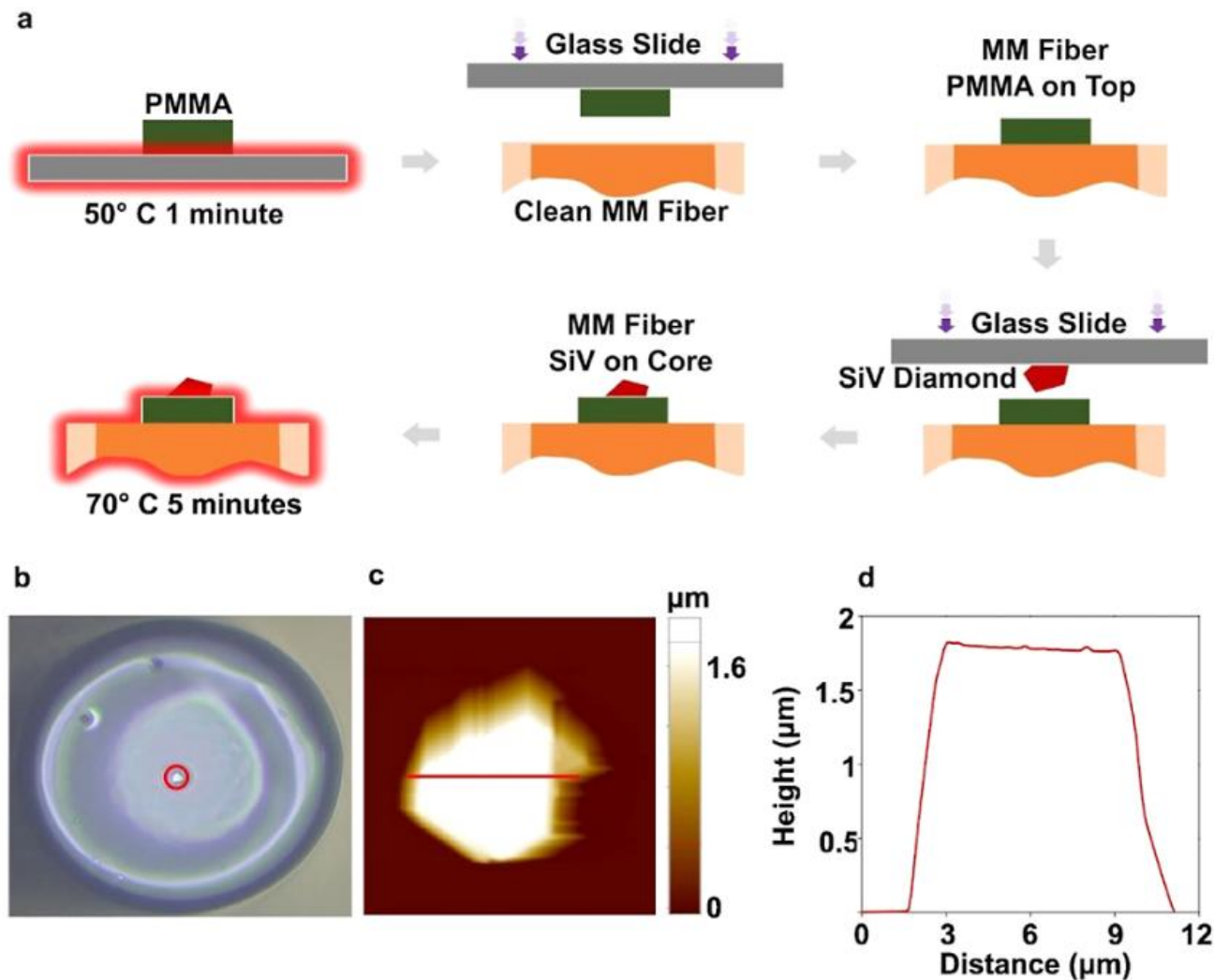
## 2. Linewidth-temperature dependent: phonon dephasing



- By placing the nanodiamonds on different locations of a microheater, we showed the corresponding temperature responses at these spots with increasing input current

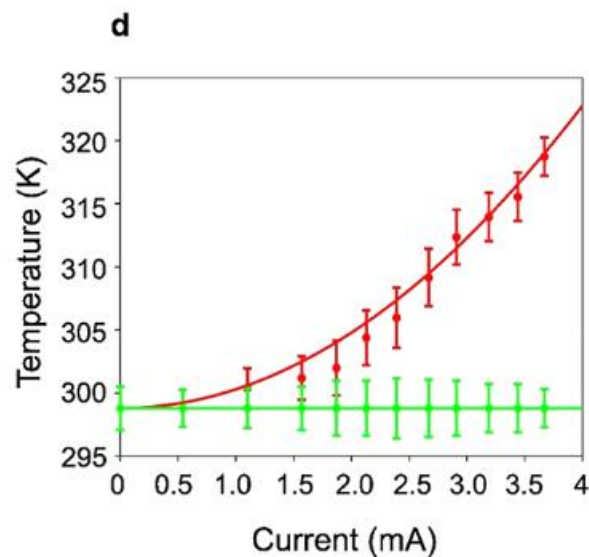
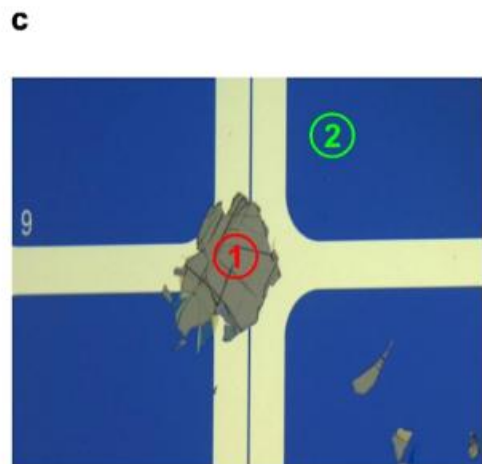
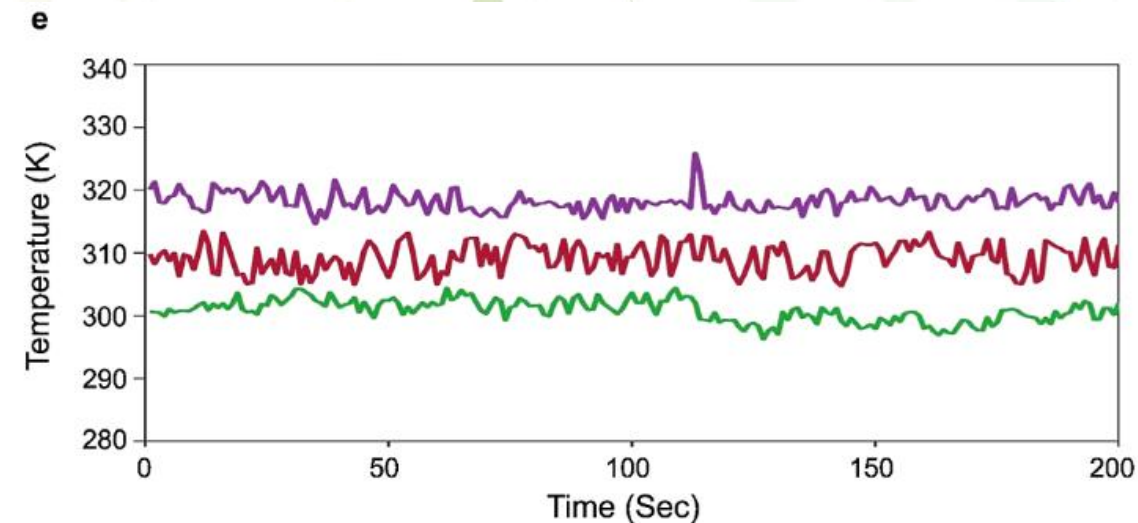
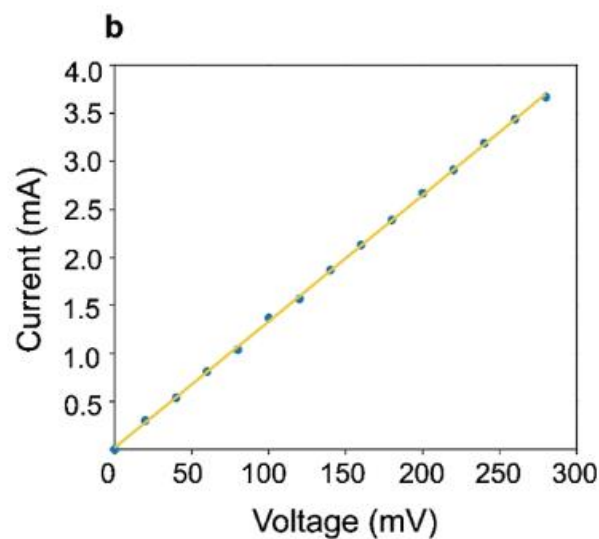
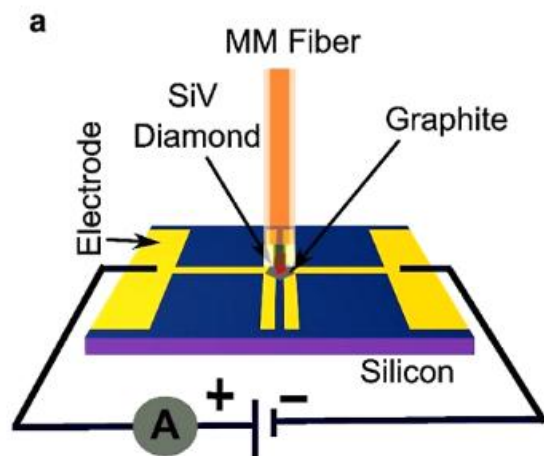


### 3. Fiber-based thermometry using PL-to-scattered-laser ratio



- Microdiamond was aligned transferred onto a multimode optical fiber using dry-transfer technique.

### 3. Fiber-based thermometry using PL-to-scattered-laser ratio



- Real-time monitoring of local temperature on a graphite-based microheater



# Thank you!

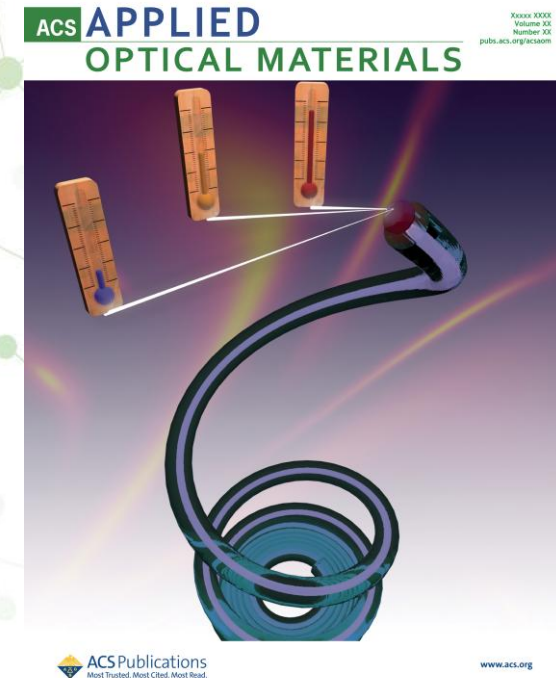
## Welcome to Toan Trong Tran Lab

The Nanoscale Electro-Thermo-Optical (NETO) Laboratory

### Collaborators:

Dr. Carlo Bradac (Trent U)  
Dr. Simon White (Griffith U)  
Prof. Weibo Gao (NTU)

Dr. Evgeny Ekimov (IHPP)  
Prof. Prineha Narang (Harvard U)  
Prof. Milos Toth (UTS)  
Prof. Igor Aharonovich (UTS)



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